

GaAs IC SPDT Switch Non-Reflective DC–2.5 GHz

iAlpha

AS002M2-12

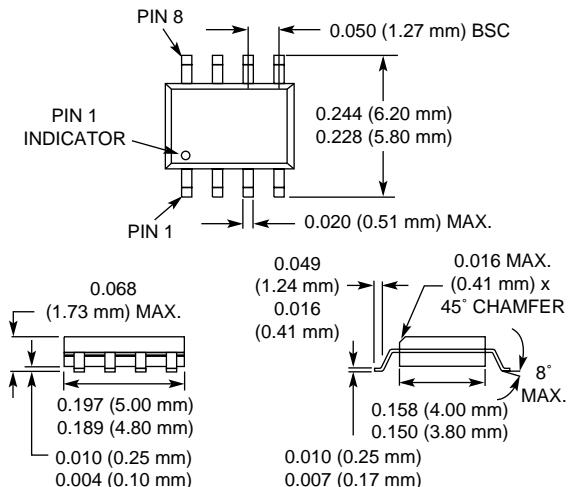
Features

- Low DC Power Consumption
- Non-Reflective
- High Isolation (40 dB @ 1 GHz)

Description

The AS002M2-12 is a low cost IC FET SPDT non-reflective switch in a plastic SOIC-8 package. The switch operates with -5, 0 V or 0, +5 V when 'floated' as shown on the following page. This general purpose SPDT switch is used in various telecommunications applications.

SOIC-8



Electrical Specifications at 25°C (0, -5 V)

Parameter ¹	Frequency ²	Min.	Typ.	Max.	Unit
Insertion Loss ³	DC–0.5 GHz DC–1.0 GHz DC–2.0 GHz DC–2.5 GHz		0.7 0.8 1.1 1.3	0.8 0.9 1.2 1.4	dB
Isolation	DC–0.5 GHz DC–1.0 GHz DC–2.0 GHz DC–2.5 GHz	42 36 27 23	46 40 30 20		dB
VSWR ⁴	DC–0.5 GHz DC–2.0 GHz DC–2.5 GHz		1.3:1 1.5:1 1.6:1	1.4:1 1.6:1 1.8:1	

Operating Characteristics at 25°C (0, -5 V)

Parameter ¹	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics ⁵	Rise, Fall (10/90% or 90/10% RF) On, Off (50% CTL to 90/10% RF) Video Feedthru			3 6 15		ns ns mV
Input Power for 1 dB Compression		0.50–2.0 GHz 0.05 GHz		+24 +16		dBm dBm
Intermodulation Intercept Point	For Two-tone Input Power +13 dBm	0.50–2.0 GHz		+46		dBm
Control Voltages	$V_{Low} = 0$ to -0.2 V @ 20 μ A Max. $V_{High} = -5$ V @ 50 μ A to -8 V @ 200 μ A Max.					

1. All measurements made in a 50 Ω system, unless otherwise specified.

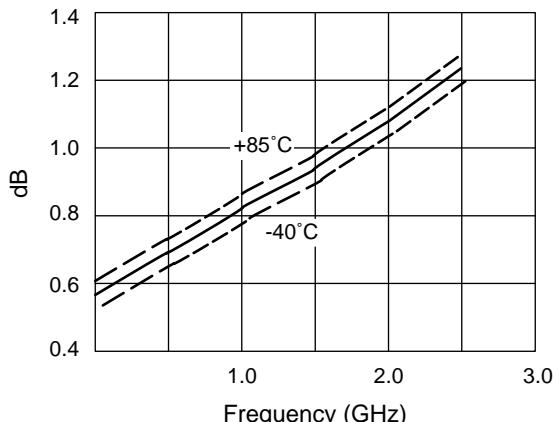
2. DC = 300 kHz.

3. Insertion loss changes by 0.003 dB/°C.

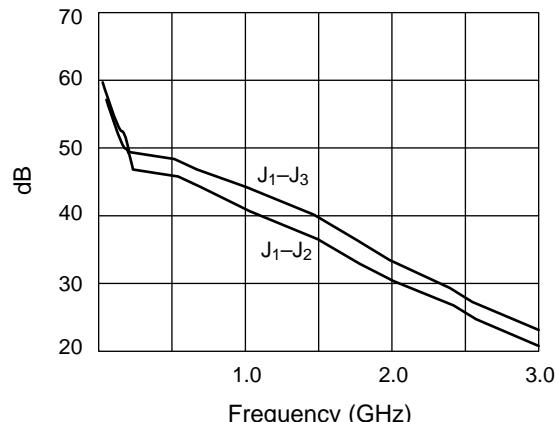
4. Input/output.

5. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.

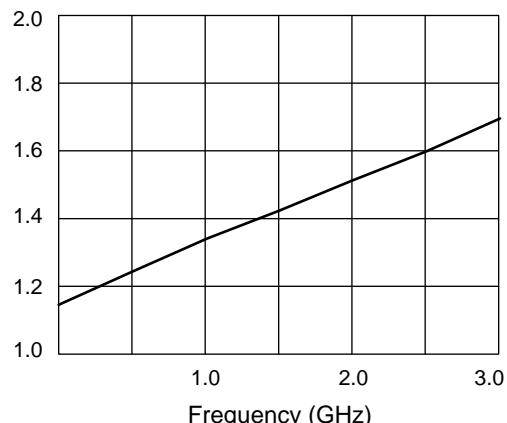
Typical Performance Data (0, -5 V)



Insertion Loss vs. Frequency



Isolation vs. Frequency



VSWR vs. Frequency

Truth Table

Negative Operation

V ₁	V ₂	J ₁ -J ₂	J ₁ -J ₃
0	-5	Insertion Loss	Isolation
-5	0	Isolation	Insertion Loss

Positive Operation

V ₁	V ₂	J ₁ -J ₂	J ₁ -J ₃
V _{High}	0	Insertion Loss	Isolation
0	V _{High}	Isolation	Insertion Loss

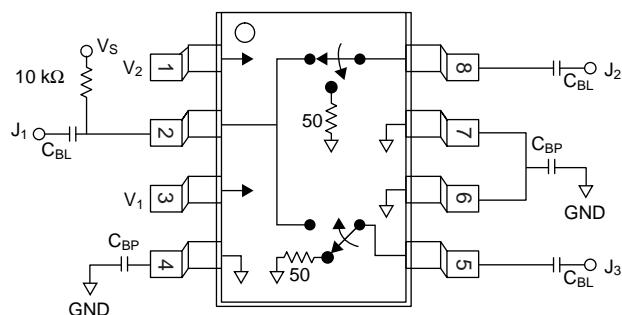
V_{High} = +5 to +8 V (V_S = V_{High} ± 0.2 V).

Absolute Maximum Ratings

Characteristic	Value
RF Input Power	2 W > 500 MHz 0/-8 V 0.5 W @ 50 MHz 0/-8 V
Control Voltage	+0.2 V, -8 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Θ _{JC}	25°C/W

Note: Exceeding these parameters may cause irreversible damage.

Pin Out



External components shown are for positive voltage operation only.
C_{BL} = 100 pF, C_{BP} = 1000 pF for operation >500 MHz.